

FMMT6520
350V PNP SILICON PLANAR HIGH VOLTAGE TRANSISTOR IN SOT23
Features and Benefits

- $BV_{CEO} > -350V$
- Maximum Continuous Collector Current $I_C = -500mA$
- 330mW power dissipation
- Complementary part number FMMT6517
- **Lead Free, RoHS Compliant (Note 1)**
- **Halogen and Antimony Free "Green" Device (Note 2)**
- **Qualified to AEC-Q101 Standards for High Reliability**

Mechanical Data

- Case: SOT-23
- UL Flammability Rating 94V-0
- Case material: molded Plastic.
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish; Solderable per MIL-STD-202, Method 208
- Weight: 0.008 grams (Approximate)

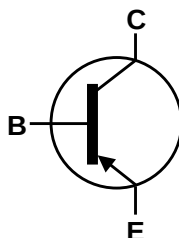
Applications

- Power switches

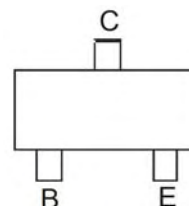
SOT-23



Top View



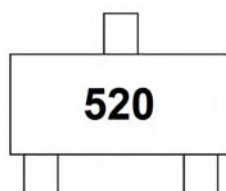
Device Symbol


 Top View
 Pin-Out

Ordering Information (Note 3)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FMMT6520TA	520	7	8	3,000

- Notes:
1. No purposefully added lead.
 2. Diodes Inc.'s "Green" Policy can be found on our website at <http://www.diodes.com>
 3. For Packaging Details, go to our website at <http://www.diodes.com>.

Marking Information


520 = Product Type Marking Code

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-350	V
Collector-Emitter Voltage	V _{CEO}	-350	V
Emitter-Base Voltage	V _{EBO}	-5	V
Continuous Collector Current	I _C	-500	mA

Thermal Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 4)	P _D	330	mW
Thermal Resistance, Junction to Ambient (Note 4)	R _{θJA}	379	°C/W
Thermal Resistance, Junction to Lead (Note 5)	R _{θJL}	350	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

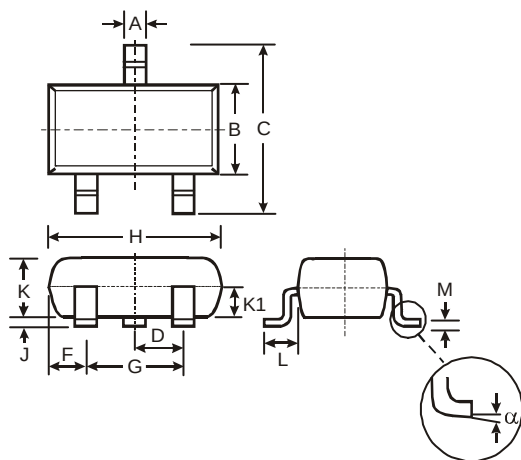
- Notes:
4. For a device surface mounted FR4 PCB with minimum recommended pad layout; high coverage of single sided 1 oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
 5. Thermal resistance from junction to solder-point (at the end of the collector lead).

Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-350			V	I _C = -100μA
Collector-Emitter Breakdown Voltage (Note 6)	BV _{CEO}	-350			V	I _C = -1mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-5			V	I _E = -10μA
Collector Cutoff Current	I _{CBO}			-50	nA	V _{CB} = -250V
Emitter Cutoff Current	I _{EBO}			-50	nA	V _{EB} = -3V
Static Forward Current Transfer Ratio (Note 6)	h _{FE}	20 30 30 20 15		200 200		I _C = -1mA, V _{CE} = -10V I _C = -10mA, V _{CE} = -10V I _C = -30mA, V _{CE} = -10V I _C = -50mA, V _{CE} = -10V I _C = -100mA, V _{CE} = -10V
Collector-Emitter Saturation Voltage (Note 6)	V _{CE(sat)}			-300 -350 -500 -1000	mV mV mV mV	I _C = -10mA, I _B = -1mA I _C = -20mA, I _B = -2mA I _C = -30mA, I _B = -3mA I _C = -50mA, I _B = -5mA
Base-Emitter Saturation Voltage (Note 6)	V _{BE(sat)}			-750 -850 -900	mV	I _C = -10mA, I _B = -1mA I _C = -20mA, I _B = -2mA I _C = -30mA, I _B = -3mA
Base-Emitter Turn-On Voltage (Note 6)	V _{BE(on)}			-2.0	V	I _C = -100mA, V _{CE} = -10V
Output Capacitance	C _{obo}			6	pF	V _{CB} = -20V, f = 1MHz
Transition Frequency	f _T	50			MHz	V _{CE} = -20V, I _C = -10mA, f = 20MHz

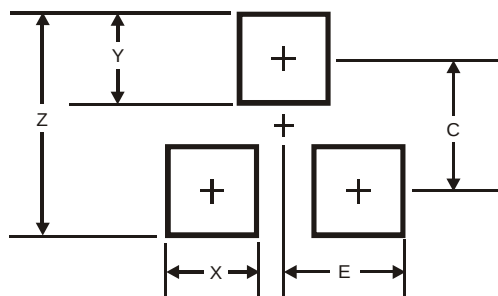
- Note:
6. Measured under pulsed conditions. Pulse width ≤ 300 μs. Duty cycle ≤ 2%

Package Outline Dimensions



SOT23			
Dim	Min	Max	Typ
A	0.37	0.51	0.40
B	1.20	1.40	1.30
C	2.30	2.50	2.40
D	0.89	1.03	0.915
F	0.45	0.60	0.535
G	1.78	2.05	1.83
H	2.80	3.00	2.90
J	0.013	0.10	0.05
K	0.903	1.10	1.00
K1	-	-	0.400
L	0.45	0.61	0.55
M	0.085	0.18	0.11
α	0°	8°	-
All Dimensions in mm			

Suggested Pad Layout



Dimensions	Value (in mm)
Z	2.9
X	0.8
Y	0.9
C	2.0
E	1.35

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